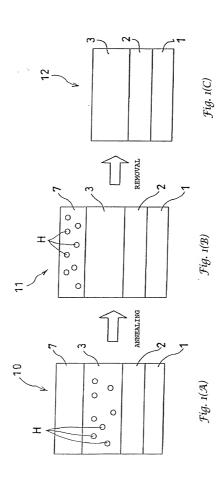
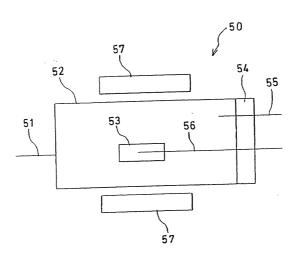
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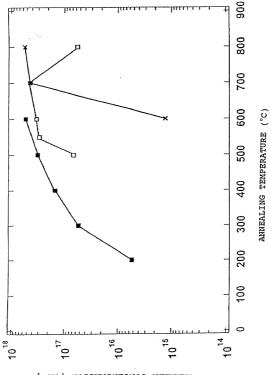
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CARRIER CONCENTRATION (cm^{-3})

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